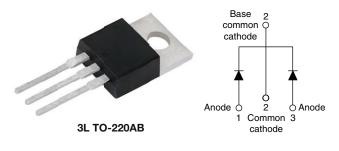
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A



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PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 20 A			
V _R	15 V			
V _F at I _F	See Electrical table			
I _{RM} max.	600 mA at 100 °C			
T _J max.	125 °C			
E _{AS}	10 mJ			
Package	3L TO-220AB			
Circuit configuration	Common cathode			

Revision: 15-Aug-17

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- · Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and qualified according to JEDEC[®]-JESD47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES U				
I _{F(AV)}	Rectangular waveform	40	А			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	700	А			
V _F	19 A _{pk} , T _J = 125 °C (per leg, typical)	0.25	V			
TJ		-55 to +125	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-STPS40L15CT-M3	UNITS			
Maximum DC reverse voltage	V _R	15	V			
Maximum working peak reverse voltage	V _{RWM}	15	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward per leg		50 % duty cycle at $T_{-} = 85 $ °C	rootangular wavoform	20				
current, see fig. 5 per device	'F(AV)	$I_{F(AV)}$ 50 % duty cycle at T _C = 85 °C, rectangular waveform		40				
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		700	А			
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330				
Repetitive avalanche current per leg	I _{AR}	$ \begin{array}{c} \mbox{Current decaying linearly to zero in 1 } \mu s \\ \mbox{Frequency limited by } T_J \mbox{ maximum } V_A = 1.5 \ x \ V_B \ typical \end{array} $		2				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH	1	10	mJ			



ROHS COMPLIANT HALOGEN

FREE





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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS		
		19 A	T _{.1} = 25 °C	-	0.41			
Forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1j=25 0	-	0.52	V		
See fig. 1	VFM ()	19 A	T ₁ = 125 °C	0.25	0.33			
		40 A	1j=125 C	0.37	0.50			
Reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	10	mA		
See fig. 2	IRM (")	T _J = 100 °C	VR - naleu VR	-	600			
Threshold voltage	V _{F(TO)}			0.1	182	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		1) = 1) maximum		7	.6	mΩ
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C			2000	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8	-	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

PARAMETER	SYMBOL	YMBOL TEST CONDITIONS		UNITS
Maximum junction temperature range	TJ		-55 to +125	°C
Maximum storage temperature range	T _{Stg}		-55 to +150	50
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation See fig. 4	1.5	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased (only for TO-220)	0.50	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK and TO-262)	40	
Approximate weight			2	g
Approximate weight			0.07	oz.
Mounting torque		Non-lubricated threads	6 (5)	kgf ⋅ cm
Mounting torque maximum		Non-Iudricated tiffeads	12 (10)	(lbf \cdot in)
Marking device		Case style 3L TO-220AB	STPS40L15CT	



VS-STPS40L15CT-M3

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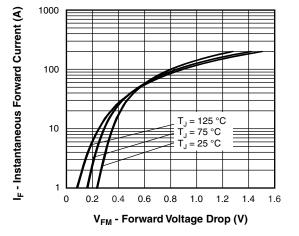


Fig. 1 - Maximum Forward Voltage Drop Characteristics

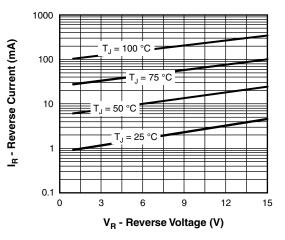


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

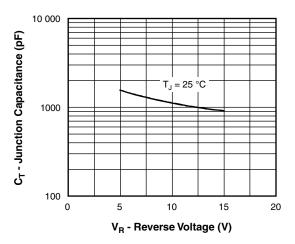


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

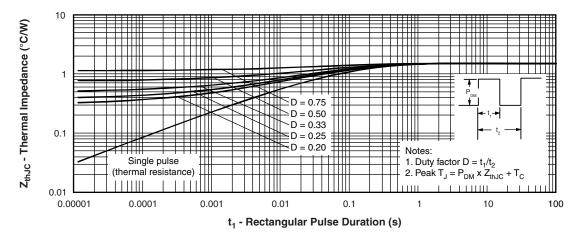
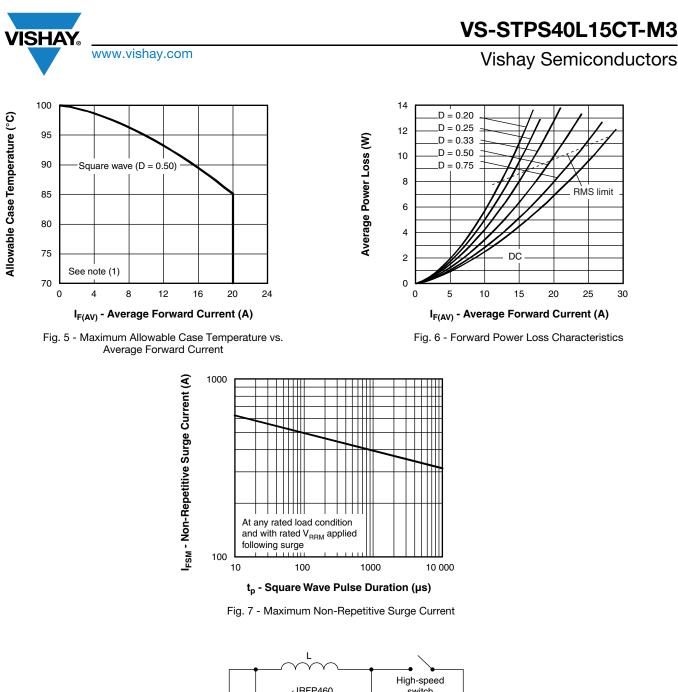


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



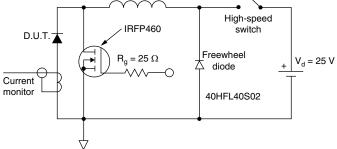


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 15-Aug-17

4

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VS-STPS40L15CT-M3



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ORDERING INFORMATION TABLE

Device code	vs-	STPS	40	L	15	ст	-M3
	(1)	(2)	(3)	(4)	(5)	(6)	()
	1	- Vish	av Sem	niconduc	tors pro	duct	
	H			PS seri		auot	
			-	ng (40 =			
	H			tage dro	-		
	H			ng (15 =			
	H		•	•	number		
				ntal digit			
	7			0	, RoHS-	complia	ont and
		-1013	- naioę	Jen-nee	, Runs-	compila	anit, anu

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-STPS40L15CT-M3	50	1000	Antistatic plastic tube			

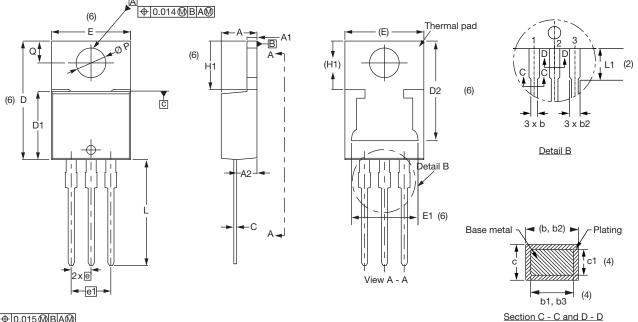
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96154					
Part marking information	www.vishay.com/doc?95028				



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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

_		
Conforms to JEDEC [®]	outline	TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Ш	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

- ⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 13-Jun-2019

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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